

Features and Benefits

- Chopper stabilized amplifier stage
- Optimized for BDC motor applications
- New miniature package / thin, high reliability package
- Operation down to 2.2V
- CMOS for optimum stability, quality, and cost
- Low I_{DD} current

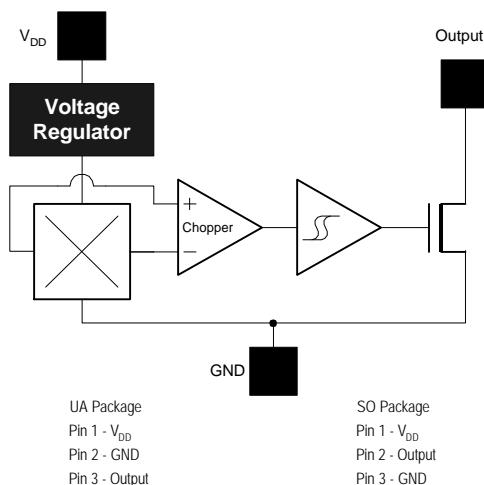
Applications

- Solid state switch
- Brushless DC motor commutation
- Speed sensing

Ordering Information

Part No.	Temperature Suffix	Package	Temperature Range
US4881	C	SO or UA	0°C to 70°C Commercial
US4881	S	SO or UA	-20°C to 85°C Industrial
US4881	K	SO or UA	-40 to 125°C Severe

Functional Diagram



Description

The US4881 is a bipolar Hall effect sensor IC fabricated from mixed signal CMOS technology. It incorporates advanced chopper stabilization techniques to provide accurate and stable magnetic switch points. There are many applications for this HED in addition to those listed above. The design specifications and performance have been optimized for commutation applications in brushless DC motors and automotive speed sensing.

The output transistor will be latched on (B_{OP}) in the presence of a sufficiently strong South pole magnetic field facing the marked side of the package. Similarly, the output will be latched off (B_{RP}) in the presence of a North field.

The SOT-23 device is reversed from the UA package. The SOT-23 output transistor will be latched on (B_{OP}) in the presence of a sufficiently strong North pole magnetic field subjected to the marked face.

Note: Static sensitive device; please observe ESD precautions. Reverse V_{DD} protection is not included. For reverse voltage protection, a 100W resistor in series with V_{DD} is recommended.

US4881 Electrical Specifications

DC operating parameters: $T_A = 25^\circ\text{C}$, $V_{DD} = 12V_{DC}$ (unless otherwise specified).

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Supply Voltage	V_{DD}	Operating	2.2		18	V
Supply Current	I_{DD}	$B < B_{OP}$	1.5	2.5	4.0	mA
Saturation Voltage	$V_{DS(on)}$	$I_{OUT} = 20 \text{ mA}, B > B_{OP}$		0.4	0.5	V
Output Leakage	I_{OFF}	$B < B_{RP}, V_{OUT} = 18V$		0.01	5.0	μA
Output Rise Time	t_r	$V_{DD} = 12V, R_L = 1.1\text{KO}, C_L = 20\text{pf}$		0.04		μs
Output Fall Time	t_f	$V_{DD} = 12V, R_L = 1.1\text{KO}, C_L = 20\text{pf}$		0.18		μs

US4881 Magnetic Specifications

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Operating Point	B_{OP}		0.5	2.0	4.5	mT
Release Point	B_{RP}		-4.5	-2.0	-0.5	mT
Hysteresis	B_{hys}		2.0	4.0	6.5	mT

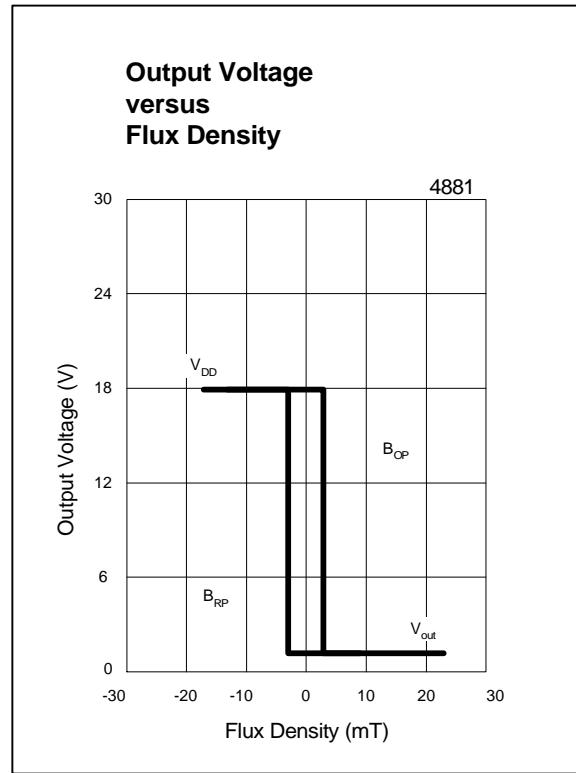
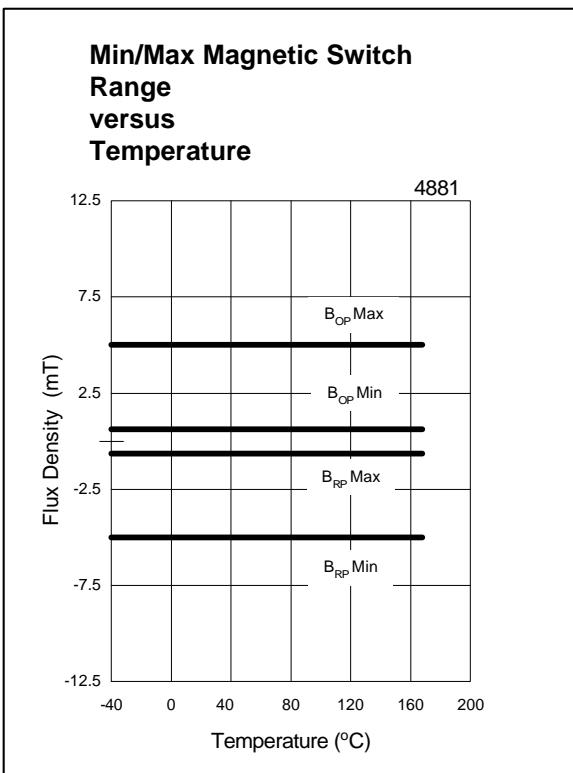
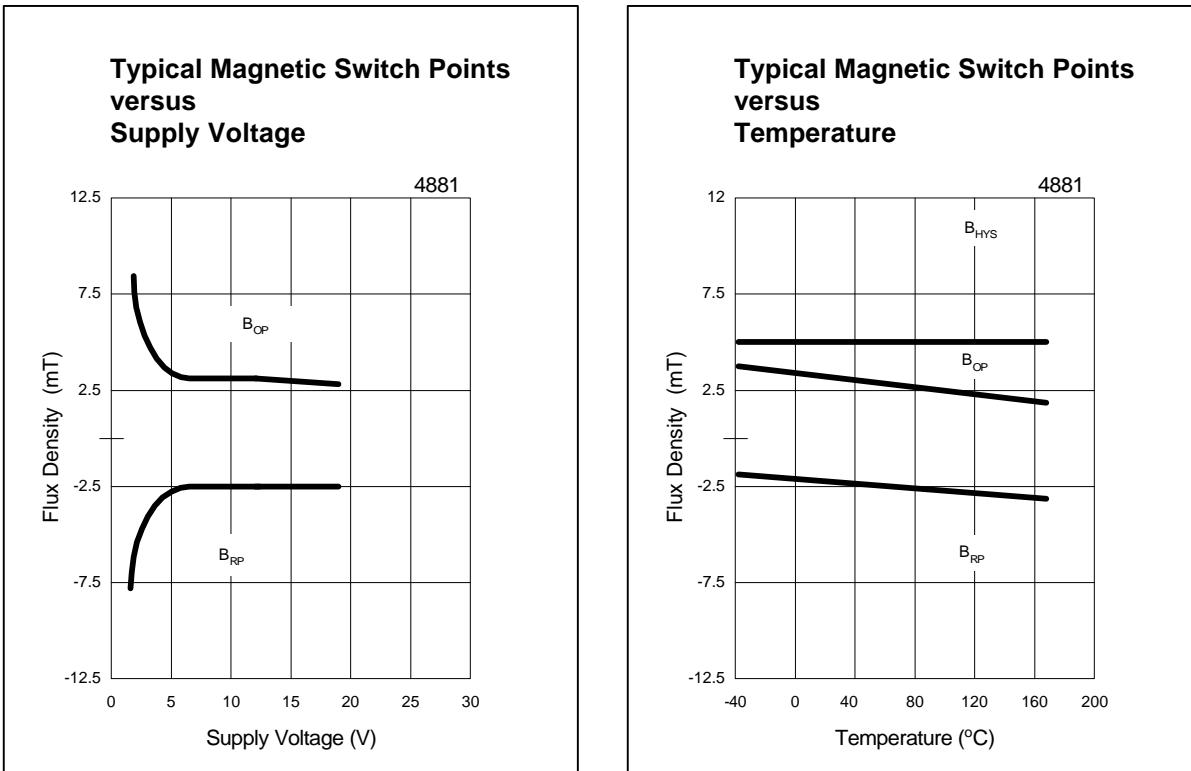
Note: 1 mT = 10 Gauss.

Absolute Maximum Ratings

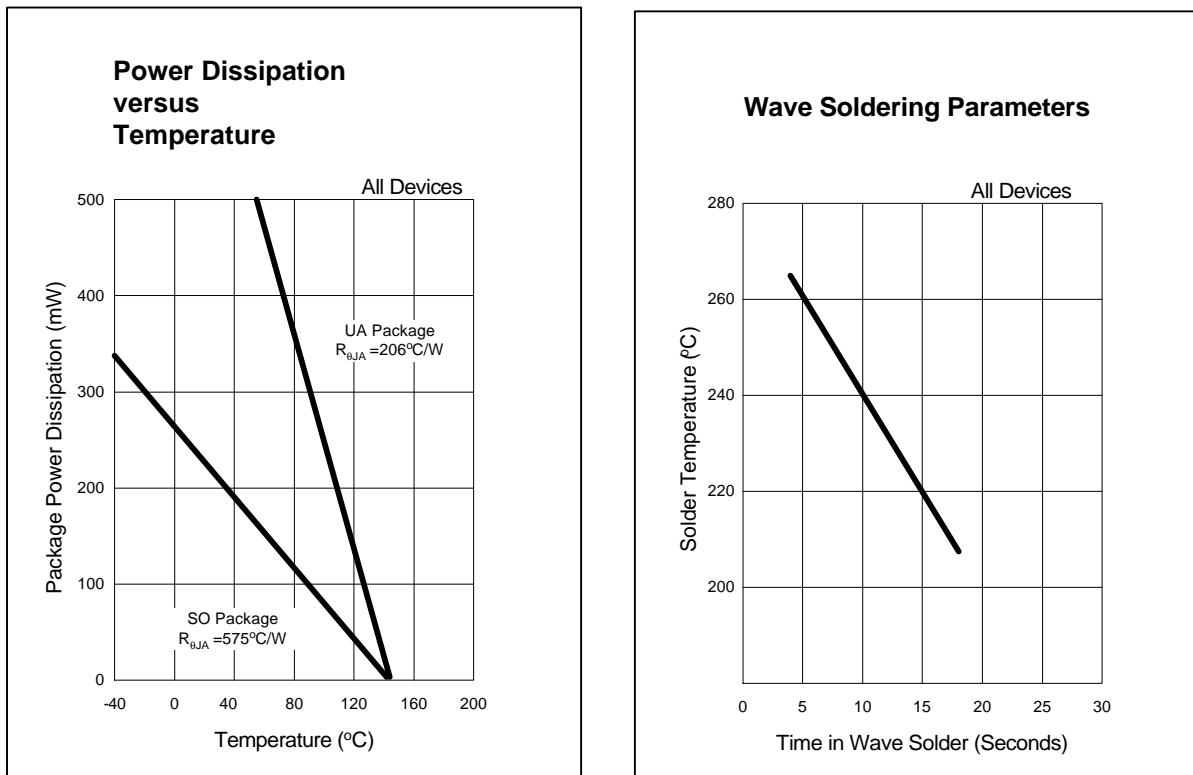
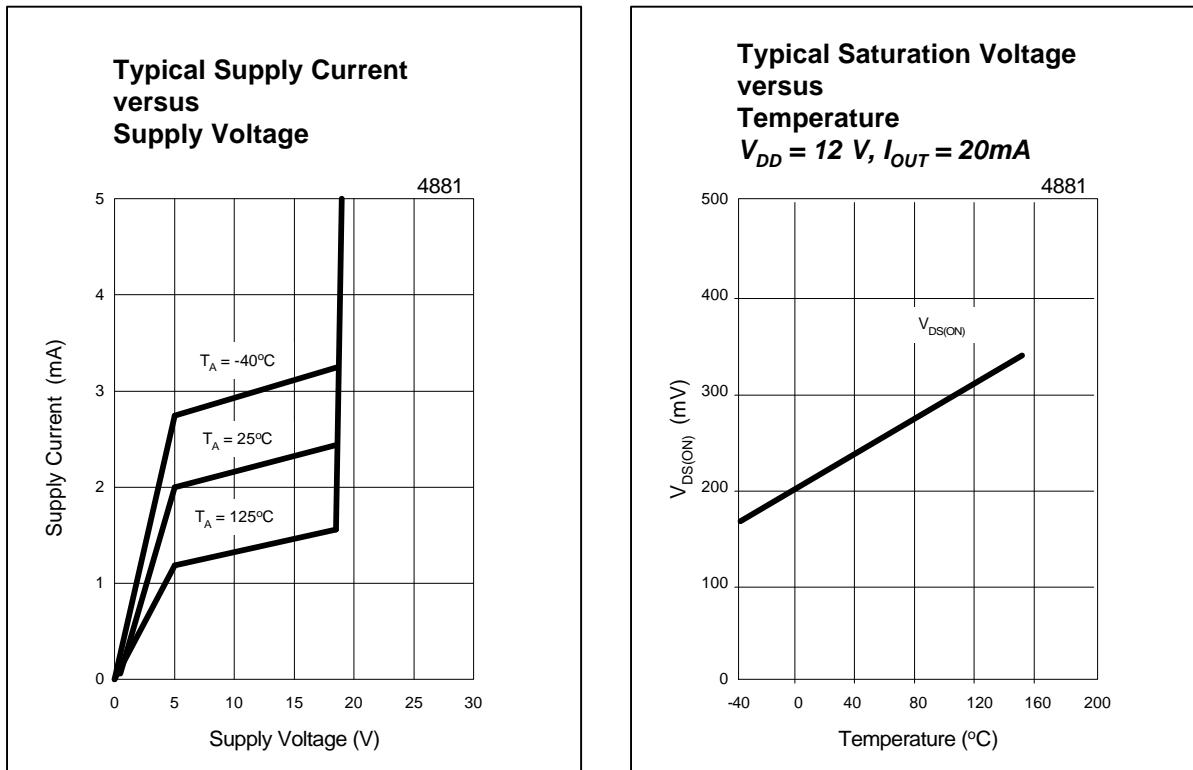
Supply Voltage (Operating), V_{DD}	18V
Supply Current (Fault), I_{DD}	50mA
Output Voltage, V_{OUT}	18V
Output Current (Fault), I_{OUT}	50mA
Power Dissipation, P_D	100mW
Operating Temperature Range, T_A	-40 to 150°C
Storage Temperature Range, T_S	-65 to 150°C
Maximum Junction Temp, T_J	175°C
ESD Sensitivity (All Pins)	+/- 4KV

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Performance Graphs



Performance Graphs



Unique Features

CMOS Hall IC Technology

The chopper stabilized amplifier uses switched capacitor techniques to eliminate the amplifier offset voltage, which, in bipolar devices, is a major source of temperature sensitive drift. CMOS makes this advanced technique possible. The CMOS chip is also much smaller than a bipolar chip, allowing very sophisticated circuitry to be placed in less space. The small chip size also contributes to lower physical stress and less power consumption.

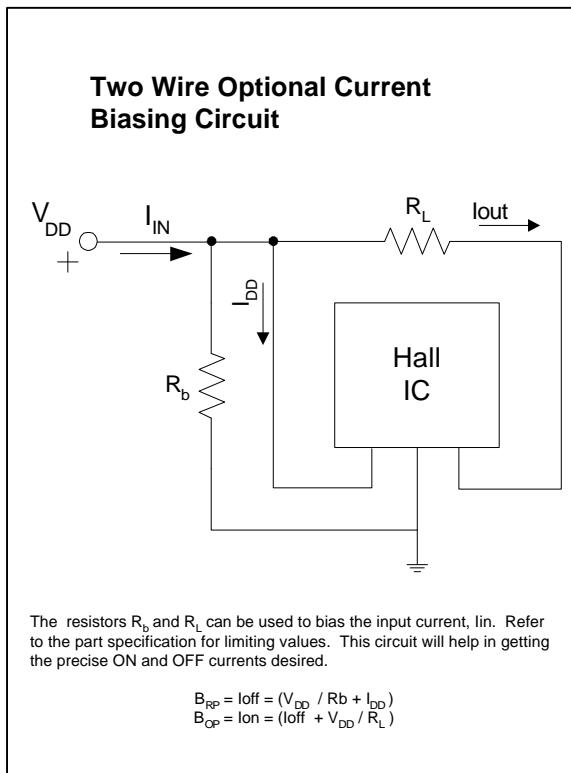
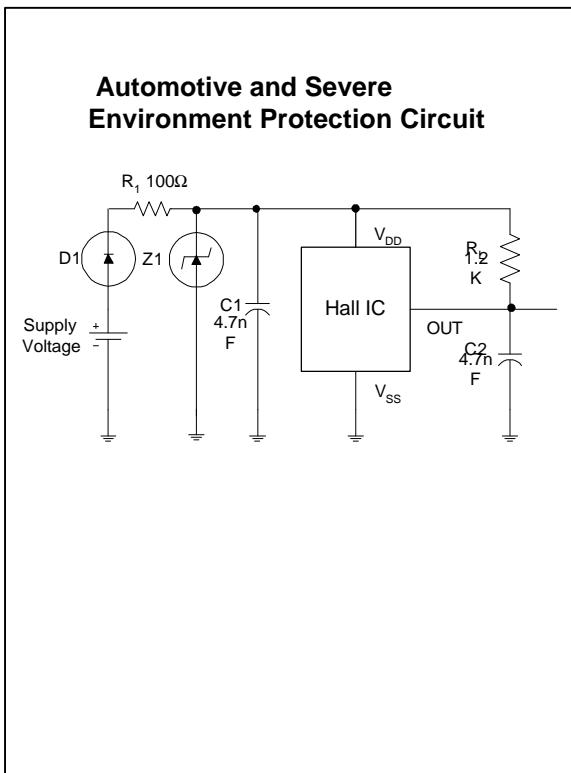
Installation Comments

Consider temperature coefficients of Hall IC and magnetics, as well as air gap and life time variations. Observe temperature limits during wave soldering.

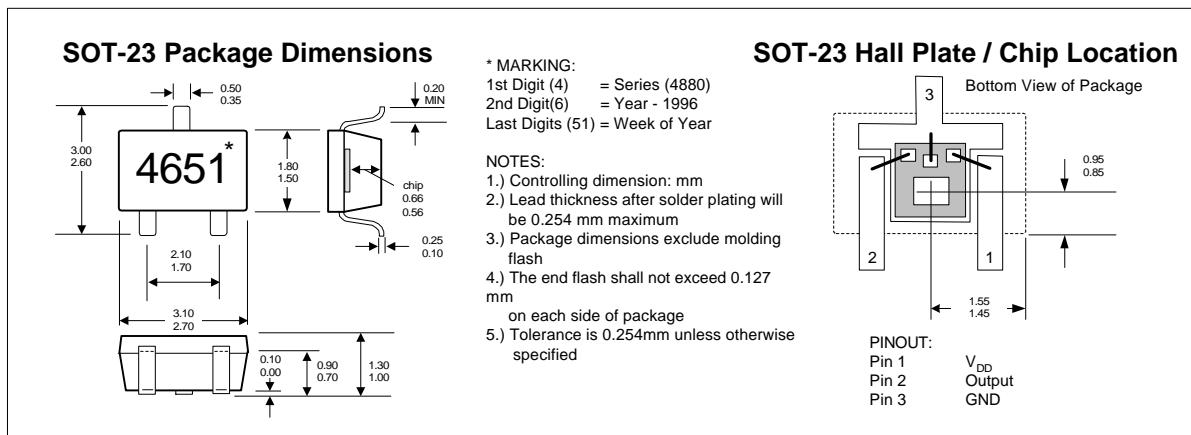
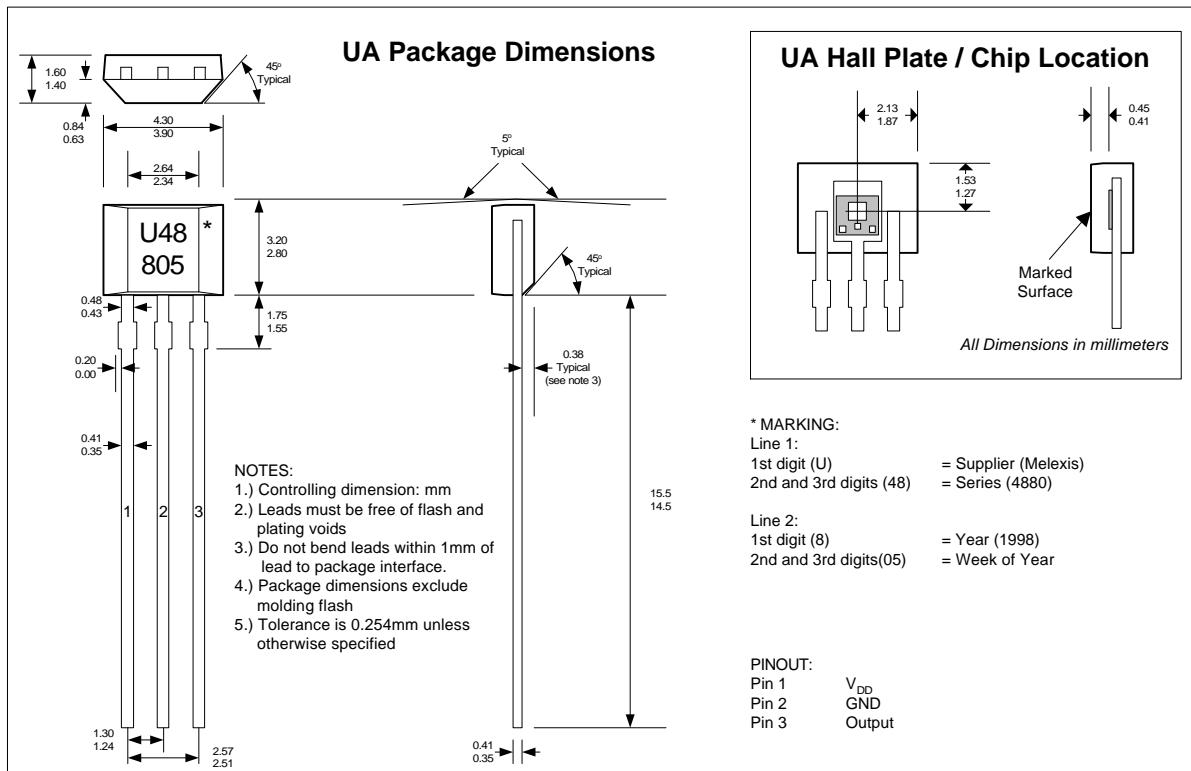
Application Comments

If reverse supply protection is desired, use a resistor in series with the V_{DD} pin. The resistor will limit the Supply Current(Fault), I_{DD} , to 50 mA. For severe EMC conditions, use the application circuit below.

Applications Examples



Physical Characteristics



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